



### **1.5A SBR** SUPER BARRIER RECTIFIER

### **Product Summary**

V <sub>RRM</sub> (V)	I <sub>O</sub> (A)	V <sub>F</sub> (MAX) (V) @ +25°C	I <sub>R(MAX)</sub> (μA) @ +25°C
100	1.5	0.85	50

## **Description and Applications**

The SBR2U100LP provides low V<sub>F</sub> and excellent reverse leakage stability at high temperatures. It is ideal for use as bypass diode and rectifier, freewheel diode or blocking diode in applications such as:

- Polarity Protection Diode
- **Recirculating Diode**
- Switching Diode
- **Bypass Diodes**





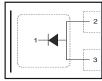
Bottom View

# **Features and Benefits**

- Low Forward Voltage Drop •
- Excellent High-Temperature Stability
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- +175°C Operating Junction Temperature
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

# **Mechanical Data**

- Case: X1-DFN1411-3 .
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 @3
- Polarity: See Below
- Weight: 2.35 mg (Approximate)



Top View Internal Schematic

## Ordering Information (Note 4)

	Part Number	Case	Packaging
	SBR2U100LP-7	X1-DFN1411-3	3,000/Tape & Reel
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.			

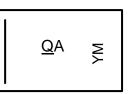
ely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# Marking Information



QA = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 4 = April)Bar = Cathode

Date	Code	Key

Year	2015	20	016	2017	2018	20	19	2020	2021	20	22	2023
Code	С		D	Е	F	(	<u> </u>	Н			J	К
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.			
Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>RM</sub>	100	v
Average Rectified Output Current	lo	1.5	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	IFSM	18	А

### **Thermal Characteristics**

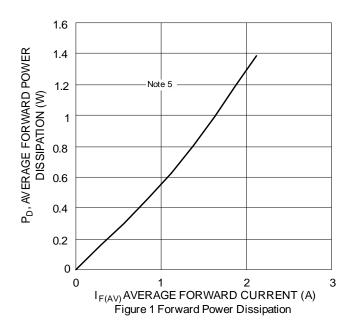
Characteris	stic	Symbol	Value	Unit
Typical Thermal Resistance Junction to	Thermal Resistance Junction to Ambient (Note 5)		100	°C/W
Operating Temperature Range	$V_R \le 80\% V_{RRM}$ $V_R \le 50\% V_{RRM}$ DC Forward Mode (Note 6)	TJ	-55 to +150 ≤ +175 ≤+200	°C
Storage Temperature Range		T <sub>STG</sub>	-55 to +175	°C

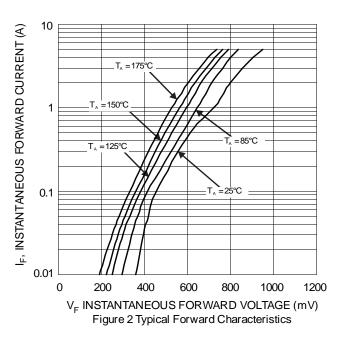
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop (Note 7)	VF		0.71 0.76	0.78 0.85	V	I <sub>F</sub> = 1A, T <sub>J</sub> = +25°C I <sub>F</sub> = 1.5A, T <sub>J</sub> = +25°C
Leakage Current (Note 7)	I <sub>R</sub>		— 60	50 —		$V_R = 100V, T_J = +25^{\circ}C$ $V_R = 100V, T_J = +125^{\circ}C$

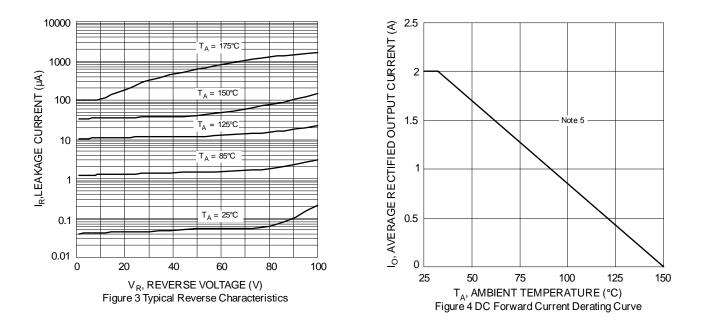
Notes:

5. 1 inch sq. copper pad, 2 oz.6. Max junction temperature guaranteed for 2 hours.7. Short duration pulse test used to minimize self-heating effect.



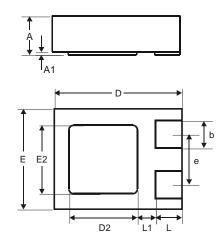






# Package Outline Dimensions

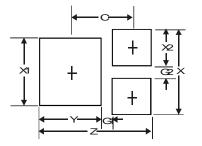
Please see http://www.diodes.com/package-outlines.html for the latest version.



	X1-DFN1411-3						
Dim	Min	Max	Тур				
Α	0.47	0.53	0.50				
A1	0.00	0.05	0.02				
b	0.25	0.35	0.30				
D	1.35	1.475	1.40				
D2	0.65	0.85	0.75				
E	1.05	1.175	1.10				
E2	0.65	0.85	0.75				
e		-	0.55				
L	0.225	0.325	0.275				
L1	_	_	0.20				
All	Dimens	ions in r	nm				

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
Z	1.38
G1	0.15
G2	0.15
Х	0.95
X1	0.75
X2	0.40
Y	0.75
С	0.76



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